

## *UTV100B* 100 Watts Pk, 28 Volt, Class AB UHF Television - Band IV & V

GENERAL DESCRIPTION The UTV100B is a COMMON EMITTER transistor capable of providing 100 Watt Peak, Class AB, RF Output Power over the band 470 - 860 MHz. The transistor includes double input and output prematching for full broadband capability. Gold Metalization and Diffused Ballasting are used to provide high reliability and supreme ruggedness. ABSOLUTE MAXIMUM RATINGS		CASE OUTLINE 55RT, STYLE 2
Maximum Power Dissipation @ 25°C	290 Watts	
Maximum Voltage and Current		
BVcbo Collector to Emiter Voltage	65 Volts	
BVceo Collector to Emitter Voltage	30 Volts	
BVebo Emitter to Base Voltage	3.5 Volts	
Ic Collector Current	15 Amps	
Maximum Temperatures		
Storage Temperature	-40 to + 150°C	
Operating Junction Temperature	+ 200 °C	
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## ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
PldB Pin Po - ref Pg η VSWR	Power Out - 1 dB Compression Power Input Power Output - Linear Power Gain - Small Sig Efficiency Load Mismatch Tolerance	F = 470 - 860  MHz $Vcc = 28  Volts$ $Icq = 300  mA (total)$ $Pout = 25  Watts Pk$	100 25 8.5 55 5:1		12.5	Watts Watts Watts dB %

\* European Test Method, Vision = -8 dB, Sideband = - 16 dB, Sound = - 7 dB

BVceo	Collector to Emitter Breakdown	Ic = 25 mA	30			Volts
BVces	Collector to Emitter Breakdown	Ic =25 mA	60			Volts
BVebo	Emitter to Base Breakdown	Ie = 30 mA	3.5			Volts
Hfe	Current Gain	Vce = 5 V, Ic = 1 A	20		120	
Cob	Output Capacitance - (each side)*	Vcb = 28V, F=1MHz		47		pF
Rθjc	Thermal Resistance	$Tc = 25 \ ^{\circ}C$			0.6	°Č/W

\* Not measureable due to internal prematch network

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## **UTV100B**





**INPUT IMPEDANCE vs FREQUENCY** 



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LOAD IMPEDANCE vs FREQUENCY Vcc = 28 V, Pout = 100W, Icq = 200 mA 12 0 SER. REACT. (OHMS) 10 -2 SER. RESIS.(OHMS) 6 R -10 <sup>\_\_]</sup> -12 900 0 400 500 600 700 800

**FREQUENCY (MHz)**